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TRANSMITTAL OF FORMAL DRAWINGS

Docket No.
YOR920030586US1 (17201)

In Re Application Of: Tze-Chiang Chen, et al.

Serial No.

10/700,085

Filing Date

11/3/2003

Confirmation No.

Unassigned

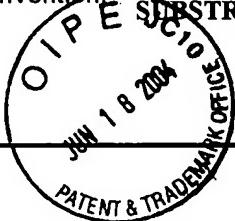
Examiner

Unassigned

Art Unit

2811

Invention: METHOD FOR FABRICATING SiGe-ON-INSULATOR (SGOI) AND Ge-ON-INSULATOR (GOI)
SUBSTRATES



Address to:
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Transmitted herewith are:

6 sheets of formal drawing(s) for this application.

- Each sheet of drawing indicates the identifying indicia suggested in 37 CFR Section 1.84(c).

A handwritten signature in black ink, appearing to read "LS".

Signature

Leslie S. Szivos, Ph.D.
Registration No. 39,394

Customer Number: 23389

Dated: June 15, 2004

I certify that this document and attached formal drawings are being deposited on 6/15/2004 with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

A handwritten signature in black ink, appearing to read "LS".

Leslie S. Szivos, Ph.D.

Typed or Printed Name of Person Mailing Correspondence